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| <b>INFORMATION DISCLOSURE<br/>CITATION</b> | ATTY. DOCKET NO.  | SERIAL NO. |
|  | 4105-73           | 10/568,770 |
|  | APPLICANT         |            |
| (Use several sheets if necessary)          | <b>CHO ET AL.</b> |            |
|  | FILING DATE       | GROUP      |
|  | March 21, 2006    | 1795       |



## **U.S. PATENT DOCUMENTS**

## FOREIGN PATENT DOCUMENTS

**OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)**

|  |   |
|--|---|
|  | Cho et al, "Tbit/inch <sup>2</sup> ferroelectric data storage ...", Applied Physics Letters, Vol. 81, No. 23, 2 Dec. 2002.                                  |
|  | Hiranaga et al, "Ferroelectric Single Crystal Recording Media ...", Japanese Journal of Applied Physics", Vol. 43, No. 4B, 2004, p. L569-L571. XP-002512248 |
|  | Terabe et al, "Microscale to Nanoscale ferroelectric domain and ...", Applied Physics Letters; Vol. 82, No. 3, 20 Jan. 2003.                                |
|  | Sones et al, "Differential etch rates in z-cut LiNbO <sub>3</sub> ...", J. Mater. Chem., 2002, 12, 295-298. XP-002511826                                    |

\*Examiner

### Date Considered

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Initial a this form with next communication to applicant.